



#### Allowable Package Power Dissipation



#### **Recommended Operating Conditions**

	Min	Max	Units
DC Output Current	0	1	А
Operating Ambient Temp.	-30	+85	°C
Operating Junction Temp.	-20	+100	°C

For the availability of parts meeting -40°C requirements, contact Allegro's Sales Representative.

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### **ELECTRICAL CHARACTERISTICS** at $T_A = +25^{\circ}$ C, $V_E = 2$ V (unless otherwise noted).

			Limits						
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units			
Channel 1									
Output Voltage	V <sub>O1</sub>	V <sub>I</sub> = 5.0 V, I <sub>O1</sub> = 10 mA	3.234	3.300	3.366	V			
	V <sub>O1(off)</sub>	$V_{E} = 0 V$			0.5	V			
Output Volt. Temp. Coeff.	a <sub>vo1</sub>	$0^{\circ}C \leq T_{J} \leq 100^{\circ}C$		±0.3	_	mV/°C			
Output Short-Circuit Current	I <sub>OM1</sub>	V <sub>I</sub> = 5.0 V, See note	1.2	_	_	А			
Line Regulation	$\Delta V_{O(\Delta VI)1}$	$V_{I} = 4.5 \text{ V} \sim 10 \text{ V}, I_{O1} = 10 \text{ mA}$		_	20	mV			
Load Regulation	$\Delta V_{O(\Delta IO)1}$	$V_{I} = 5.0 \text{ V}, I_{O1} = 0 \text{ A} \sim 1.0 \text{ A}$			30	mV			
Dropout Voltage	V <sub>Imin</sub> - V <sub>O1</sub>	I <sub>O1</sub> = 1.0 A		—	0.6	V			
Ripple Rejection Ratio	PSRR	$V_{\rm I}$ = 5.0 V, 100 Hz $\leq$ f $\leq$ 120 Hz		60	_	dB			
Channel 2									
Output Voltage	V <sub>O2</sub>	V <sub>I</sub> = 5.0 V, I <sub>O2</sub> = 10 mA	2.450	2.500	2.550	V			
	V <sub>O2(off)</sub>	$V_{E} = 0 V$	_		0.5	V			
Output Volt. Temp. Coeff.	a <sub>vo2</sub>	$0^{\circ}C \leq T_{J} \leq 100^{\circ}C$		±0.3	_	mV/°C			
Output Short-Circuit Current	I <sub>OM2</sub>	V <sub>I</sub> = 5.0 V, See note	1.2	—		А			
Line Regulation	$\Delta V_{O(\Delta VI)2}$	$V_{I} = 4.5 \text{ V} \sim 10 \text{ V}, I_{O2} = 10 \text{ mA}$			20	mV			
Load Regulation	$\Delta V_{O(\Delta IO)2}$	$V_{I} = 5.0 \text{ V}, I_{O2} = 0 \text{ A} \sim 1.0 \text{ A}$			30	mV			
Dropout Voltage	$V_{Imin}$ - $V_{O2}$	I <sub>O2</sub> = 1.0 A			0.6	V			
Ripple Rejection Ratio	PSRR	$V_{I}$ = 5.0 V, 100 Hz $\leq$ f $\leq$ 120 Hz		60	_	dB			
Logic									
Ground Terminal Current	I <sub>GND</sub>	$V_{\rm I}$ = 5.0 V, $I_{\rm O}$ = 0 mA, $V_{\rm E}$ = 2.0 V		1.0	1.5	mA			
		$V_{I} = 5.0 \text{ V}, V_{E} = 0 \text{ V}$			0.5	mA			
Enable Input Voltage	V <sub>EH</sub>	Output ON	2.0	—		V			
	V <sub>EL</sub>	Output OFF	_		0.8	V			
Enable Input Current	I <sub>EH</sub>	V <sub>E</sub> = 2.7 V		0	5.0	μA			
	I <sub>EL</sub>	$V_{E} = 0.4 V$		-12	-100	μA			
Thermal Shutdown	TJ	$I_0 = 10 \text{ mA}$	135	150		°C			

Typical values are given for circuit design information only.

Note: Output short-circuit current is at point where output voltage has decreased 5%.

0.6

0.1

0

3.33

3.32

€ 3.31

3.30 3.29 3.28 3.28

3.27

3.26

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INPUT VOLTAGE, VI (V)

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1.0

0

20

40 ) 60 Time (μs) 80

100

0.8

OUTPUT CURRENT, lo (A)



Linear Drs Regulators **SI-3002KWF** 1 A, Low-Dropout, Dual Output, 2.5 V & 3.3 V Regulator **TYPICAL CHARACTERISTICS (cont.)**  $(V_1 = 5.0 V, T_A = 25^{\circ}C)$ Chan. 2 Low-Voltage Behavior Chan. 2 Overcurrent Protection 3.0 2.5 lo = 0 A  $V_1 = 4.5$ Vo (V) OUTPUT VOLTAGE, Vo (V) 2.0 lo = 1 A OUTPUT VOLTAGE, Vi = 8 V 1.5 10 V 1.0 0.5 0 OUTPUT CURRENT, Io (A) INPUT VOLTAGE, VI (V) ■ Chan. 2 Line Regulation Chan. 2 Load Regulation Chan. 2 Transient Response 2.53 2.53 Ch2 Output Voltage (V) 2.60 2.52 2.52 Vo2 2.50 ≥<sup>2.51</sup> % (A) 9/ 351 2.50 2.49 2.48 Vi = 10 V lo = 0 AVi = 8 V 2.40 A '32.50 2.49 2.48 2.48 Vi = 5 V Co = 47 µF Vi = 5 V Vi = 3.3 Output Current (A) lo2 1.0 2.47 2.47 0.5 2.46 2.46 Ö 0.2 0.4 0.6 0.8 0 20 40 60 Time (μs) 80 100 INPUT VOLTAGE, Vi (V) OUTPUT CURRENT, Io (A) ENABLE Control Voltage ENABLE Control Current Thermal Protection 10 Vo ENABLE CONTROL CURRENT, IE (JJA) 5.0 Voi OUTPUT VOLTAGE, Vo (V) OUTPUT VOLTAGE, Vo (V) 0 Voz Vc -5.0 -10 -15 -20 0 0 1.0 1.5 2.0 ENABLE CONTROL VOLTAGE, VE (V) 0.5 2.5 3.0 0 0.5 1.5 2.5 3.0 0 20 40 60 80 100 120 140 160 180 1.0 2.0 ENABLE CONTROL VOLTAGE, VE (A) JUNCTION TEMPERATURE, TJ (°C)

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#### **APPLICATIONS INFORMATION**

or

**Input Capacitor** (C<sub>1</sub>,  $0.1 \sim 10 \mu$ F). This is necessary either when the input line includes inductance or when the wiring is long.

**Output Capacitor** ( $C_0$ , >22  $\mu$ F). This device is not designed for a use with a very low ESR output capacitor such as a ceramic capacitor. Output oscillation may occur with that kind of capacitor.

**ENABLE Input.** The ENABLE (control) input features an internal pull-up resistor. Leaving this input open causes the output to turn on.

**Parallel Operation.** Parallel operation to increase load current is not permitted.

**Determination of DC Input Voltage.** The minimum input voltage  $V_I(min)$  should be higher than the sum of the fixed output voltage and the maximum rated dropout voltage.

**Overcurrent Protection.** The SI-3000KWF series has a built-in fold-back type overcurrent protection circuit, which limits the output current at a start-up mode. It thus cannot be used in applications that require current at the start-up mode such as:

(1) constant-current load,

(2) power supply with positive and negative outputs to common load (a center-tap type power supply), or(3) raising the output voltage by putting a diode or a resistor between the device ground and system ground.

**Thermal Protection.** Circuitry turns off the pass transistor when the junction temperature rises above 135°C. It is intended only to protect the device from failures due to excessive junction temperatures and should not imply that output short circuits or continuous overloads are permitted.

**Heat Radiation and Reliability.** The reliability of the IC is directly related to the junction temperature  $(T_J)$  in its operation. Accordingly, careful consideration should be given to heat dissipation.

The inner frame on which the integrated circuit is mounted is connected to the GND terminal (pin 3). Therefore, it is very effective for heat radiation to enlarge the copper area that is connected to the GND terminal. The graph on page 2 illustrates the effect of thermal resistance on the allowable package power dissipation.

The junction temperature  $(T_J)$  can be determined from either of the following equations:

$$\mathbf{T}_{\mathbf{J}} = (\mathbf{P}_{\mathbf{D}} \times \mathbf{R}_{\theta \mathbf{J} \mathbf{A}}) + \mathbf{T}_{\mathbf{A}}$$

$$T_{I} = (P_{D} \times R_{arc}) + T_{C}$$

where 
$$P_D = I_{O1}(V_I - V_{O1}) + I_{O2}(V_I - V_{O2})$$
 and  $R_{\theta IC} = 7^{\circ}C/W.$ 



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## SI-3002KWF 1 A, Low-Dropout, Dual Output, 2.5 V & 3.3 V Regulator

# **Dimensions in Millimeters**

